

SC13151TP

THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:
VAN GOMPEL, TONI D., et al.

Application No.: 10/737115

Filed: 12-16-2003

Docket No.: SC13151TP

§
§
§
§
§
§
§
§
§

Patent No.: 7037857 B2

Issue Date: 05-02-2006

Examiner: Scott Geyer

Group Art Unit: 2812

Title: METHOD FOR ELIMINATING OF EXCESSIVE FIELD OXIDE RECESS FOR THIN SI
SOI

Certificate of Submission

I hereby certify that this correspondence is being submitted to the USPTO,
Alexandria, VA.

- ☐ Addressed per C.F.R. § 1.1(a) and deposited with the United States Postal
Service with sufficient postage as first class mail.
- ☐ Facsimile transmitted in accordance with C.F.R. §1.6(d).
- ☒ Submitted electronically via EFS in accordance with "Legal Framework for
EFS Web".

March 4, 2008
Date of Submission

Teresa Shepherd
Signature

Teresa Shepherd
Printed Name of Person Signing Certificate

Commissioner for Patents
Alexandria, VA 22313

SUBMISSION OF CERTIFICATE OF CORRECTION

Dear Commissioner:

Enclosed is a Certificate of Correction listing error(s) in the subject patent.
Please enter these corrections. Since the errors appear to be on the part of the United
States Patent Office, there should be no charge.

3/3/08
Date

Respectfully submitted,

Michael J. Balconi-Lamica
BALCONI-LAMICA, MICHAEL J.
Attorney for Applicant(s)
Registration No. 34291
Telephone No. (512) 996-6839
Facsimile No. (512) 996-6854

**UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION**

Page 1 of 1

PATENT NO.: 7037857 B2
APPLICATION NO: 10/737115
DATE: 12-16-2003
FIRST NAMED INVENTOR: VAN GOMPEL, TONI D.

It is certified that error appears in the above-identified patent and that said Letters Patent are hereby corrected as shown below:

In Column 8, Line 51, Claim No. 18:

Change "further comprises suicide" to --further comprises silicide--

MAILING ADDRESS OF SENDER (Please do not use customer number below)

Freescall Semiconductor, Inc.
Law Department
7700 West Parmer Lane PL02
Austin, TX 78729